Ref #	Hits	Search Query	DBs	Default Operat or	Plura Is	Time Stamp
S2	7440	(AFM STEM SEM nanotip\$3 probe atomic adj force scanning near microscope) and ((si silicon) near (n p dop\$4) n-type p-type) and etch\$3	US-PGPU B; USPAT	OR	ON	2005/09/28 11:22
S3	1023	S2 and (((si silicon) near (n dop\$4) n-type) with etch\$3) and (((si silicon) near (p dop\$4) p-type) with etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:25
S4	960	S2 and (((si silicon) near (n dop\$4) n-type) with etch\$3) same (((si silicon) near (p dop\$4) p-type) with etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:25
S5	943	S2 and (((si silicon) near (n dop\$4) n-type) with etch\$3) with (((si silicon) near (p dop\$4) p-type) with etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:25
S6	358	S2 and (((si silicon) near n n-type) with etch\$3) with (((si silicon) near p p-type) with etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:26
S7	4	S2 and (((si silicon) near n n-type) near etch\$3) with (((si silicon) near p p-type) near etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:27
S8	17	S2 and (((si silicon) near n n-type) near2 etch\$3) with (((si silicon) near p p-type) near2 etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:27
S9	40	S2 and (((si silicon) near n n-type) near4 etch\$3) with (((si silicon) near p p-type) near4 etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 11:27

S10	46	("3977925" "4312117" "4668865" "4806755" "4943719").PN. OR ("5021364").URPN.	US-PGPU B; USPAT; USOCR	OR	OFF	2005/09/28 11:38
S11	13	S8 not S7	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2005/09/28 11:43
S12	23	S9 not (S7 S8)	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2005/09/28 11:43
S13	5	(cant?lever AFM STEM SEM nanotip\$3 probe atomic scanning microscope) near2 tip with ((si silicon) near (n p dop\$4) n-type p-type) with etch\$3	US-PGPU B; USPAT	OR	ON	2005/09/28 11:50
S14	70	("3977925" "4307507" "4312117" "4668865" "4685996" "4806755" "4912822" "4916002" "4943719" "4968382" "4968585").PN. OR ("4943719" "5066358"). URPN.	US-PGPU B; USPAT; USOCR	OR	OFF	2005/09/28 11:52
S16	92	S10 S14	US-PGPU B; USPAT; USOCR	OR	OFF	2005/09/28 11:52
S15	24	S10 and S14	US-PGPU B; USPAT; USOCR	OR	OFF	2005/09/28 11:59

S17 68	S16 not S15	US-PGPU B; USPAT; USOCR	OR	OFF	2005/09/28 11:59
S18 28	(US-5021364-\$ or US-5066358-\$ or US-4943719-\$ or US-6011261-\$ or US-5811017-\$ or US-5717132-\$ or US-5386720-\$ or US-5386710-\$ or US-5367165-\$ or US-6862921-\$ or US-6862921-\$ or US-6862921-\$ or US-6400166-\$ or US-6358426-\$ or US-69982-\$ or US-5994160-\$ or US-5595942-\$ or US-5537863-\$ or US-5537863-\$ or US-5116462-\$ or US-4968585-\$ or US-4916002-\$).did. or (US-4307507-\$).did.	USPAT	OR	OFF	2005/09/28

S19	18	(US-6694805-\$ or US-6059982-\$ or US-6011261-\$ or US-5994160-\$ or US-5929643-\$ or US-5717132-\$ or US-5580827-\$ or US-5537863-\$ or US-5469733-\$ or US-5272913-\$ or US-5272913-\$ or US-5116462-\$ or US-4968585-\$ or US-4943719-\$ or US-4916002-\$ or US-4307507-\$).did.	USPAT	OR	OFF	2005/09/28 12:32
S21	0	S20 and ((square rectang\$4 pyramid\$4) near (mask\$3 photoresist opening pit hole expos\$4)) and (deposit\$4 near (first second) near (dop\$3 si silicon)) and (etch\$3 near (Si silicon))	US-PGPU B; USPAT	OR	ON	2005/09/28 12:41
S22	0	S20 and ((square rectang\$4 pyramid\$4) near2 (mask\$3 photoresist opening pit hole expos\$4)) and (deposit\$4 near2 (first second) near2 (dop\$3 si silicon)) and (etch\$3 near2 (Si silicon))	US-PGPU B; USPAT	OR	ON	2005/09/28 12:41
S23	8	S20 and ((square rectang\$4 pyramid\$4) with (mask\$3 photoresist opening pit hole expos\$4)) and (deposit\$4 with (first second) near2 (dop\$3 si silicon)) and (etch\$3 with (Si silicon))	US-PGPU B; USPAT	OR	ON	2005/09/28 12:43

S24	32	S20 and ((square rectang\$4 pyramid\$4) with (mask\$3 photoresist opening pit hole expos\$4)) and (deposit\$4 with (first second) with (dop\$3 si silicon)) and (etch\$3 with (Si silicon))	US-PGPU B; USPAT	OR	ON	2005/09/28 12:44
S26	4	S25 and S24	US-PGPU B; USPAT	OR	ON	2005/09/28 12:44
S27	3	S23 and S25	US-PGPU B; USPAT	OR	ON	2005/09/28 12:44
S28	4	S26 S27	US-PGPU B; USPAT	OR	ON	2005/09/28 12:57
S1	5998	(AFM STEM SEM nanotip\$3 probe atomic adj force scanning near microscope) and (si near (n p dop\$4) n-type p-type) and etch\$3	US-PGPU B; USPAT	OR	ON	2005/09/28 12:58
S30	4	S29 and (n p dop\$4 n-type p-type)	US-PGPU B; USPAT	OR	ON	2005/09/28 13:11
S32	1	S31 not S30	US-PGPU B; USPAT	OR	ON	2005/09/28 13:11
S29	5	S23 not S28	US-PGPU B; USPAT	OR	ON	2005/09/28 13:13
S33	0	S29 not S23	US-PGPU B; USPAT	OR	ON	2005/09/28 13:13

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S20	497	("3623219" "3665241"	US-PGPU	OR	OFF	2005/09/28
		"3693417" "3731191"	В;			13:14
		"3746587" "3755704"	USPAT;			
		"3888708" "3894332"	USOCR			
,		"3921022" "3970887"				
		"3977925" "3998678"				
		"4008412" "4095133"				
		"4171234" "4193836"				
,		"4205418" "4282311"				
		"4284712" "4297312"				
		"4307507" "4312117"				
		"4371803" "4396459"				
		"4428111" "4574625"				
		"4585991" "4614119"				
		"4618397" "4668865"				
		"4685996" "4724318"				
		"4735396" "4786545"				
		"4801866" "4806755"				
		"4861990" "4894538"				
		"4908112" "4916002"				
		•				
		"4943719" "4956923"				
		"4964946" "4968585" "4009016" "5021264"				
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	,	"5047637" "5051379" "5066359" "5070699"				
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		"5116462" "5132533"				
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		"5201992" "5202263"				,
		"5204210" "5221415"				
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		"5742172" "5772325"				
		"5811017" "5883387"				
		"Re33387").PN. OR				
		("4307507" "4685996"			ĺ	
		"4916002" "4943719"				
		"4968585" "5021364"				
		"5116462" "5272913"				
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1	į	"5717137" "50706/3"	I	I	I	ı l

S34	24	S24 not S23	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	OFF	2005/09/28 13:15
S36	0	S35 not S34	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/28 13:16
S37	2	S34 not S35	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/28 13:16
S35	22	S34 and (p n p-type n-type dop\$4)	US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/09/28 13:36
S31	5	S29 and (n p dop\$4 n-type p-type etch\$3)	US-PGPU B; USPAT	OR	ON	2005/09/28 14:03
S40	59	S39 and (n p dop\$4 n-type p-type)	US-PGPU B; USPAT	OR	ON	2005/09/28 14:03
S41	207	(n-type p-type dop\$3) near (Si silicon) with (\$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/09/28 14:55
S25	38	S20 and electrochemical\$2 with etch\$3	US-PGPU B; USPAT	OR	ON	2005/09/28 14:57

S42	23	S41 and electrochemical\$2 with etch\$3	US-PGPU B; USPAT	OR	ON	2005/09/28 14:57
S38	22	S34 and (p n p-type n-type dop\$4)	US-PGPU B; USPAT	OR	ON	2005/09/28 15:07
S43	23	S42 and (p n p-type n-type dop\$4)	US-PGPU B; USPAT	OR	ON	2005/09/28 15:07
S39	83	("3977925" "4008412" "4307507" "4312117" "4668865" "4724318" "4806755" "5057047" "5214282" "5272330" "5354985" "5357787" "5410151" "5489774" "5580827" "5811926"). PN. OR ("4943719" "5883387" "5962958"). URPN,	US-PGPU B; USPAT; USOCR	OR	OFF	2005/09/28 15:21
S45	17	(n-type p-type dop\$3) near (Si silicon) near (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 15:36
S46	1	deposit\$4 near (n-type p-type dop\$3) near (Si silicon) near (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 15:38
S48	1	deposit\$4 near4 (n-type p-type dop\$3) near4 (Si silicon) near4 (\$2AFM \$6probe \$6tip stylus)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/10/03 15:43
S49	56	deposit\$4 same (n-type p-type dop\$3) same (Si silicon) same (\$2AFM \$6probe \$6tip stylus)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/10/03 15:43
S47	11	deposit\$4 near4 (n-type p-type dop\$3) near4 (Si silicon) near4 (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 16:00

S50	42	deposit\$4 with (n-type p-type dop\$3) with (Si silicon) with (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 16:01
S51	31	S50 not S47	US-PGPU B; USPAT	OR	ON	2005/10/03 16:01
S53	123	dop\$3 near (Si silicon) with (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 16:32
S44	218	(n-type p-type dop\$3) near (Si silicon) with (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 16:33
S55	74	S54 and electrochemical\$2 near4 etch\$3	US-PGPU B; USPAT	OR	ON	2005/10/03 16:34
S56	48	S55 not S52	US-PGPU B; USPAT	OR	ON	2005/10/03 16:34
S52	26	S44 and electrochemical\$2 near4 etch\$3	US-PGPU B; USPAT	OR	ON	2005/10/03 16:39
S54	1336	(n-type p-type dop\$3) with (Si silicon) same (\$2AFM \$6probe \$6tip stylus)	US-PGPU B; USPAT	OR	ON	2005/10/03 16:39
S57	194	(n-type p-type dop\$3) with (Si silicon) same (\$2AFM \$6probe \$6tip stylus)	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/10/03 16:39
S58	0	S57 and electrochemical\$2 near4 etch\$3	US-PGPU B; USPAT	OR	ON	2005/10/03 16:39
S59	5	S57 and electrochemical\$2 near4 etch\$3	EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2005/10/03 16:39